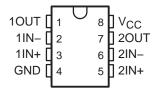
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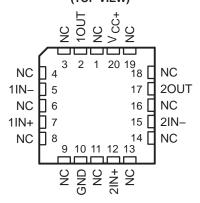
- Wide Supply Range:
  - Single Supply . . . 3 V to 32 V (26 V for LM2904)
  - or Dual Supplies . . . ±1.5 V to ±16 V (±13 V for LM2904)
- Low Supply-Current Drain, Independent of Supply Voltage . . . 0.7 mA Typ
- Common-Mode Input Voltage Range Includes Ground, Allowing Direct Sensing Near Ground
- Low Input Bias and Offset Parameters:
  - Input Offset Voltage . . . 3 mV Typ
     A Versions . . . 2 mV Typ
  - Input Offset Current . . . 2 nA Typ
  - Input Bias Current . . . 20 nA Typ A Versions . . . 15 nA Typ
- Differential Input Voltage Range Equal to Maximum-Rated Supply Voltage . . . 32 V (26 V for LM2904)
- Open-Loop Differential Voltage Amplification . . . 100 V/mV Typ
- Internal Frequency Compensation

## description/ordering information

These devices consist of two independent, high-gain, frequency-compensated operational amplifiers designed to operate from a single LM158, LM158A . . . JG PACKAGE
LM258, LM258A . . . D, DGK, OR P PACKAGE
LM358 . . . D, DGK, P, PS, OR PW PACKAGE
LM358A . . . D, DGK, P, OR PW PACKAGE
LM2904 . . . D, DGK, P, PS, OR PW PACKAGE
(TOP VIEW)



LM158, LM158A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

supply over a wide range of voltages. Operation from split supplies also is possible if the difference between the two supplies is 3 V to 32 V (3 V to 26 V for the LM2904), and  $V_{CC}$  is at least 1.5 V more positive than the input common-mode voltage. The low supply-current drain is independent of the magnitude of the supply voltage.

Applications include transducer amplifiers, dc amplification blocks, and all the conventional operational amplifier circuits that now can be implemented more easily in single-supply-voltage systems. For example, these devices can be operated directly from the standard 5-V supply used in digital systems and easily can provide the required interface electronics without additional  $\pm$ 5-V supplies.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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### description/ordering information (continued)

#### **ORDERING INFORMATION**

TA	V <sub>IO</sub> max AT 25°C	MAX TESTED VCC	PACKAGE	<u>:</u> †	ORDERABLE PART NUMBER	TOP-SIDE MARKING
			PDIP (P)	Tube of 50	LM358P	LM358P
				Tube of 75	LM358D	
			SOIC (D)	Reel of 2500	LM358DR	LM358
	7 mV	30 V	SOP (PS)	Reel of 2000	LM358PSR	L358
			T0000 (D)40	Tube of 150	LM358PW	1.050
			TSSOP (PW)	Reel of 2000	LM358PWR	L358
0°C to 70°C			MSOP/VSSOP (DGK)	Reel of 2500	LM358DGKR	M5_‡
			PDIP (P)	Tube of 50	LM358AP	LM358AP
			2010 (5)	Tube of 75	LM358AD	1140504
	_ ,,		SOIC (D)	Reel of 2500	LM358ADR	LM358A
l	3 mV	30 V		Tube of 150	LM358APW	
			TSSOP (PW)	Reel of 2000	LM358APWR	L358A
			MSOP/VSSOP (DGK)	Reel of 2500	LM358ADGKR	M6_‡
			PDIP (P)	Tube of 50	LM258P	LM258P
	,		2010 (2)	Tube of 75	LM258D	
	5 mV	30 V	SOIC (D)	Reel of 2500	LM258DR	LM258
			MSOP/VSSOP (DGK)	Reel of 2500	LM258DGKR	M2_‡
–25°C to 85°C			PDIP (P)	Tube of 50	LM258AP	LM258AP
	_ ,,	30 V	2010 (2)	Tube of 75	LM258AD	
	3 mV		SOIC (D)	Reel of 2500	LM258ADR	LM258A
			MSOP/VSSOP (DGK)	Reel of 2500	LM258ADGKR	M3_‡
			PDIP (P)	Tube of 50	LM2904P	LM2904P
			2010 (5)	Tube of 75	LM2904D	1140004
1			SOIC (D)	Reel of 2500	LM2904DR	LM2904
	7 mV	26 V	SOP (PS)	Reel of 2000	LM2904PSR	L2904
			T0000 (D)40	Tube of 150	LM2904PW	1,000.4
-40°C to 125°C			TSSOP (PW)	Reel of 2000	LM2904PWR	L2904
			MSOP/VSSOP (DGK)	Reel of 2500	LM2904DGKR	MB_‡
	,		SOIC (D)	Reel of 2500	LM2904VQDR	L2904V
	7 mV	32 V	TSSOP (PW)	Reel of 2000	LM2904VQPWR	L2904V
		95.7	SOIC (D)	Reel of 2500	LM2904AVQDR	L2904AV
	2 mV	32 V	TSSOP (PW)	Reel of 2000	LM2904AVQPWR	L2904AV
	5 V	0637	CDIP (JG)	Tube of 50	LM158JG	LM158JG
5500 to 40500	5 mV	30 V	LCCC (FK)	Tube of 55	LM158FK	LM158FK
–55°C to 125°C	0\/	20.1/	CDIP (JG)	Tube of 50	LM158AJG	LM158AJG
	2 mV	30 V	LCCC (FK)	Tube of 55	LM158AFK	LM158AFK

<sup>†</sup>Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

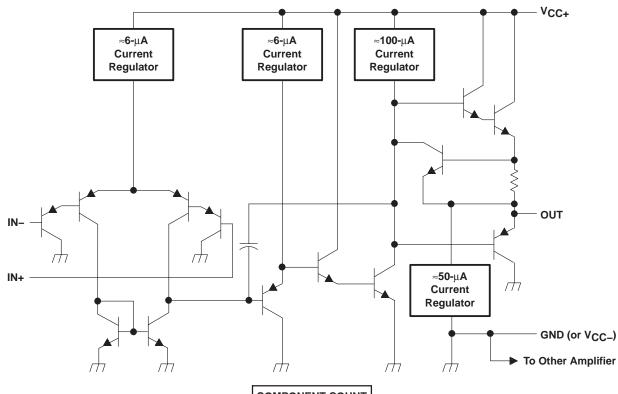


<sup>&</sup>lt;sup>‡</sup> The actual top-side marking has one additional character that designates the assembly/test site.

## symbol (each amplifier)



## schematic (each amplifier)



COMPONENT COUNT							
Epi-FET	1						
Diodes	2						
Resistors	7						
Transistors	51						
Capacitors	2						

# LM158, LM158A, LM258, LM258A LM358, LM358A, LM2904, LM2904V DUAL OPERATIONAL AMPLIFIERS

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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

		LM158, LM158A LM258, LM258A LM358, LM358A LM2904V	LM2904	UNIT		
Supply voltage, V <sub>CC</sub> (see Note 1)	±16 or 32	±13 or 26	V			
Differential input voltage, V <sub>ID</sub> (see Note 2)		±32	±26	V		
Input voltage, V <sub>I</sub> (either input)		-0.3 to 32	-0.3 to 26	V		
Duration of output short circuit (one amplifier) to ground at (or below) 25°C free-air temperature ( $V_{CC} \le 15 \text{ V}$ ) (see Note 3)		Unlimited	Unlimited			
	D package	97	97			
	DGK package	172	172			
Package thermal impedance, $\theta_{JA}$ (see Notes 4 and 5)	P package	85	85	°C/W		
	PS package	95	95			
	PW package	149	149			
Parkers the small beautiful advers 0 (see Notes 0 and 7)	FK package	5.61		0000		
Package thermal impedance, $\theta_{\mbox{\scriptsize JC}}$ (see Notes 6 and 7)	JG package	14.5	°C/W			
	LM158, LM158A	-55 to 125				
On anothing from all to an another and an T	LM258, LM258A	-25 to 85		°C		
Operating free-air temperature range, T <sub>A</sub>	LM358, LM358A	0 to 70		°C		
	LM2904	-40 to 125	-40 to 125			
Operating virtual junction temperature, TJ		150	150	°C		
Case temperature for 60 seconds	FK package	260		°C		
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG package	300	300	°C		
Storage temperature range, T <sub>Stg</sub>		-65 to 150	-65 to 150	°C		

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential voltages and V<sub>CC</sub> specified for measurement of I<sub>OS</sub>, are with respect to the network ground terminal.

- 2. Differential voltages are at IN+ with respect to IN-.
- 3. Short circuits from outputs to  $V_{\hbox{\footnotesize{CC}}}$  can cause excessive heating and eventual destruction.
- Maximum power dissipation is a function of T<sub>J</sub>(max), θ<sub>JA</sub>, and T<sub>A</sub>. The maximum allowable power dissipation at any allowable ambient temperature is P<sub>D</sub> = (T<sub>J</sub>(max) – T<sub>A</sub>)/θ<sub>JA</sub>. Operating at the absolute maximum T<sub>J</sub> of 150°C can affect reliability.
- 5. The package thermal impedance is calculated in accordance with JESD 51-7.
- 6. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JC}$ , and  $T_C$ . The maximum allowable power dissipation at any allowable case temperature is  $P_D = (T_J(max) T_C)/\theta_{JC}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.
- 7. The package thermal impedance is calculated in accordance with MIL-STD-883.



P	PARAMETER	TEST CONDITIONS†		T <sub>A</sub> ‡		LM158 LM258			LM358		UNIT	
					MIN	TYP§	MAX	MIN	TYP§	MAX		
.,		$V_{CC} = 5 \text{ V to}$		25°C		3	5		3	7		
VIO	Input offset voltage	$V_{IC} = V_{ICR}(n)$ $V_{O} = 1.4 \text{ V}$	nin) <sup>,</sup>	Full range			7			9	mV	
$\alpha_{V_{IO}}$	Average temperature coefficient of input offset voltage			Full range		7			7		μV/°C	
IIO	Input offset current	V <sub>O</sub> = 1.4 V		25°C		2	30		2	50	nA	
10		VO = 1.1 V		Full range			100			150		
$\alpha_{I_{IO}}$	Average temperature coefficient of input offset current			Full range		10			10		pA/°C	
I <sub>IB</sub>	Input bias current	V <sub>O</sub> = 1.4 V		25°C		-20	-150		-20	-250	nA	
'IB	input blub builtent	VO = 1.4 V		Full range			-300			-500	117 (	
VICR Common-mode		V <sub>CC</sub> = 5 V to	MAX	25°C	0 to	1.5		0 to VCC -	1.5		V	
input voltage range			Full range	0 to			0 to			·		
		$R_L \ge 2 k\Omega$		25°C	VCC -	1.5		VCC -	1.5			
V <sub>OH</sub>	High-level	R <sub>L</sub> ≥ 10 kΩ		25°C							V	
OH	output voltage	V <sub>CC</sub> = MAX	$R_L = 2 k\Omega$	Full range	26			26				
	Low-level		$R_L \ge 10 \text{ k}\Omega$	Full range	27	28		27	28			
VOL	output voltage	$R_L \le 10 \text{ k}\Omega$		Full range		5	20		5	20	mV	
۸. ه	Large-signal differential	V <sub>CC</sub> = 15 V, V <sub>O</sub> = 1 V to 1	1 \/	25°C	50	100		25	100		\//m\/	
AVD	voltage amplification	R <sub>L</sub> ≥ 2 kΩ		Full range	25			15			V/mV	
CMRR	Common-mode rejection ratio	$V_{CC} = 5 \text{ V to}$ $V_{IC} = V_{ICR}(n)$		25°C	70	80		65	80		dB	
ksvr	Supply-voltage rejection ratio (∆VDD/∆VIO)	V <sub>CC</sub> = 5 V to	MAX	25°C	65	100		65	100		dB	
V <sub>O1</sub> /V <sub>O2</sub>	Crosstalk attenuation	f = 1 kHz to 2	0 kHz	25°C		120			120		dB	
		V <sub>C</sub> C = 15 V,	Course	25°C	-20	-30		-20	-30			
	Outract comment	$V_{ID} = 1 V, V_{O} = 0$	Source	Full range	-10			-10			A	
10	Output current	V <sub>CC</sub> = 15 V,	Cint	25°C	10	20		10	20		mA	
		$V_{ID} = -1 \text{ V},$ $V_{O} = 15 \text{ V}$	Sink	Full range	5			5				
IO	Output current	V <sub>ID</sub> = −1 V, V		25°C	12	30		12	30		μΑ	
los	Short-circuit output current	$V_{CC}$ at 5 V, $Q_{CC}$	SND at -5 V,	25°C		±40	±60		±40	±60	mA	
_	Supply current	$V_0 = 2.5 \text{ V, N}$		Full range		0.7	1.2		0.7	1.2		
ICC	(two amplifiers)	V <sub>CC</sub> = MAX, No load	$V_0 = 0.5 V_0$	Full range		1	2		1	2	mA	

<sup>†</sup> All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. MAX V<sub>CC</sub> for testing purposes is 26 V for the LM2904 and 30 V for others.



<sup>‡</sup> Full range is  $-55^{\circ}$ C to 125°C for LM158,  $-25^{\circ}$ C to 85°C for LM258, 0°C to 70°C for LM358, and  $-40^{\circ}$ C to 125°C for LM2904. § All typical values are at  $T_A = 25^{\circ}$ C.

## LM158, LM158A, LM258, LM258A LM358, LM358A, LM2904, LM2904V DUAL OPERATIONAL AMPLIFIERS SLOS068P - JUNE 1976 - REVISED SEPTEMBER 2004

	DADAMETED	TEST COME	NTIONS†	T. T	L	M2904			
	PARAMETER	TEST COND	JIIONSI	T <sub>A</sub> ‡	MIN	TYP§	MAX	UNIT	
			Non A dovison	25°C		3	7		
V	Input offeet voltege	$V_{CC} = 5 \text{ V to MAX},$	Non-A devices	Full range			10	\/	
V <sub>IO</sub>	Input offset voltage	$V_{IC} = V_{ICR(min)},$ $V_{O} = 1.4 \text{ V}$	A cuffix devices	25°C		1	2	mV	
		Ŭ.	A-suffix devices	Full range			4		
$\alpha_{V_{\text{IO}}}$	Average temperature coefficient of input offset voltage			Full range		7		μV/°C	
				25°C		2	50		
	Input offset current		Non-V device	Full range			300		
liO		V <sub>O</sub> = 1.4 V		25°C		2	50	nA	
			V-suffix device	Full range			150		
α <sub>I</sub> IO	Average temperature coefficient of input offset current			Full range		10		pA/°C	
				25°C		-20	-250		
I <sub>IB</sub>	IB Input bias current V <sub>O</sub> = 1.4 V			Full range			-500	nA	
	Common-mode input voltage		25°C	0 to V <sub>CC</sub> – 1.	5				
VICR	range	$V_{CC} = 5 \text{ V to MAX}$		Full range	0 to V <sub>CC</sub> -2			V	
		$R_L \ge 10 \text{ k}\Omega$		25°C	V <sub>CC</sub> – 1	.5			
		V <sub>C</sub> C = MAX,	R <sub>L</sub> = 2 kΩ	Full range	22				
Vон	High-level output voltage	Non-V device	R <sub>L</sub> ≥ 10 kΩ	Full range	23	24		V	
		V <sub>CC</sub> = MAX,	$R_L = 2 k\Omega$	Full range	26				
		V-suffix device	R <sub>L</sub> ≥ 10 kΩ	Full range	27	28			
VOL	Low-level output voltage	R <sub>L</sub> ≤ 10 kΩ	_	Full range		5	20	mV	
^	Large-signal differential	V <sub>CC</sub> = 15 V, V <sub>O</sub> = 1	V to 11 V,	25°C	25	100		V/mV	
AVD	voltage amplification	$R_L \ge 2 k\Omega$		Full range	15				
CMDD	Common mode maio etion metio	$V_{CC} = 5 \text{ V to MAX},$	Non-V device	25°C	50	80		10	
CMRR	Common-mode rejection ratio	VIC = VICR(min)	V-suffix device	25°C	65	80		dB	
ksvr	Supply-voltage rejection ratio $(\Delta V_{DD}/\Delta V_{IO})$	V <sub>CC</sub> = 5 V to MAX		25°C	65	100		dB	
V <sub>O1</sub> /V <sub>O2</sub>	Crosstalk attenuation	f = 1 kHz to 20 kHz		25°C		120		dB	
		V <sub>CC</sub> = 15 V,		25°C	-20	-30		mA	
		$V_{ID} = 1 \text{ V}, V_{O} = 0$	Source	Full range	-10			mA	
		V <sub>CC</sub> = 15 V,		25°C	10	20		mA	
IO	Output current	$V_{ID} = -1 \text{ V},$ $V_{O} = 15 \text{ V}$	Sink	Full range	5			mA	
		V <sub>ID</sub> = −1 V,	Non-V device	25°C		30		1.	
		$V_0 = 200 \text{ mV}$	V-suffix device	25°C	12	40		μΑ	
los	Short-circuit output current	V <sub>CC</sub> at 5 V, GND at	$-5 \text{ V, V}_{O} = 0$	25°C		±40	±60	mA	
loo	Supply current (two amplifiers)	$V_O = 2.5 \text{ V}$ , No load	Full range		0.7	1.2	m ^		
ICC	Supply current (two amplifiers)	$V_{CC} = MAX, V_O = 0$	Full range		1	2	mA		

<sup>†</sup> All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. MAX V<sub>CC</sub> for testing purposes is 26 V for the LM2904, 32 V for the LM2904V, and 30 V for others.



<sup>‡</sup> Full range is –55°C to 125°C for LM158, –25°C to 85°C for LM258, 0°C to 70°C for LM358, and –40°C to 125°C for LM2904.

<sup>§</sup> All typical values are at  $T_A = 25$ °C.

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D	DAMETER	TEST CONDITIONS†		+	LM158A			LM258A			LIMIT
Ρ/	ARAMETER	TEST CON	DITIONS	T <sub>A</sub> ‡	MIN	TYP§	MAX	MIN	TYP§	MAX	UNIT
V <sub>IO</sub>	Input offset voltage	$V_{CC} = 5 \text{ V to}$ $V_{IC} = V_{ICR(r)}$	30 V,	25°C			2		2	3	mV
	A	V <sub>O</sub> = 1.4 V		Full range			4			4	
$\alpha_{V_{\text{IO}}}$	Average temperature coefficient of input offset voltage			Full range		7	15*		7	15	μV/°C
lio	Input offset current	V <sub>O</sub> = 1.4 V		25°C		2	10		2	15	nA
	Average			Full range			30			30	
$\alpha_{I_{IO}}$	temperature coefficient of input offset current			Full range		10	200		10	200	pA/°C
I <sub>IB</sub>	Input bias current	V <sub>O</sub> = 1.4 V	Vo = 1.4.V			-15	-50		-15	-80	nA
'ID	input blub burrent	VO = 1.4 V		Full range			-100			-100	
V <sub>ICR</sub>	Common-mode	V <sub>CC</sub> = 30 V		25°C	0 to	1.5		0 to	1.5		V
inp inp	input voltage range	VCC = 00 V		Full range	0 to V <sub>CC</sub> -	2		0 to V <sub>CC</sub> -	2		v
	LPak laval	$R_L \ge 2 k\Omega$		25°C	Vcc -	1.5		Vcc -	1.5		
	High-level output voltage	V <sub>CC</sub> = 30 V	$R_L = 2 k\Omega$ $R_L \ge 10 k\Omega$	Full range Full range	26 27	28		26 27	28		V
VOL	Low-level output voltage	R <sub>L</sub> ≤ 10 kΩ		Full range		5	20		5	20	mV
	Large-signal	V <sub>CC</sub> = 15 V,		25°C	50	100		50	100		
AVD	differential voltage amplification	$V_O = 1 \text{ V to } 1$ $R_L \ge 2 \text{ k}\Omega$	1 V,	Full range	25			25			V/mV
CMRR	Common-mode rejection ratio			25°C	70	80		70	80		dB
k <sub>SVR</sub>	Supply-voltage rejection ratio (ΔV <sub>DD</sub> /ΔV <sub>IO</sub> )			25°C	65	100		65	100		dB
V <sub>O1</sub> /V <sub>O2</sub>	Crosstalk attenuation	f = 1 kHz to 2	0 kHz	25°C		120			120		dB
		V <sub>CC</sub> = 15 V,	Source	25°C	-20	-30	-60	-20	-30	-60	
		$V_{ID} = 1 V$ , $V_{O} = 0$	Source	Full range	-10			-10			A
IO	Output current	V <sub>CC</sub> = 15 V,	Cink	25°C	10	20		10	20		mA
		$V_{ID} = -1 V,$ $V_{O} = 15$	Sink	Full range	5			5			1
		V <sub>ID</sub> = -1 V, V	O = 200 mV	25°C	12	30		12	30		μΑ
Ios	Short-circuit output current	$V_{CC}$ at 5 V, 0 $V_{O} = 0$	GND at -5 V,	25°C		±40	±60		±40	±60	mA
	Cumply ourroat (to-	V <sub>O</sub> = 2.5 V, No load		Full range		0.7	1.2		0.7	1.2	
ICC	Supply current (two amplifiers)	V <sub>CC</sub> = MAX, No load	$V_0 = 0.5 V$ ,	Full range		1	2		1	2	mA

<sup>\*</sup>On products compliant to MIL-PRF-38535, this parameter is not production tested.



<sup>†</sup> All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. MAX V<sub>CC</sub> for testing purposes is 26 V for LM2904 and 30 V for others.

<sup>‡</sup> Full range is -55°C to 125°C for LM158A, -25°C to 85°C for LM258A, and 0°C to 70°C for LM358A.

<sup>§</sup> All typical values are at  $T_A = 25$ °C.

## LM158, LM158A, LM258, LM258A LM358, LM358A, LM2904, LM2904V DUAL OPERATIONAL AMPLIFIERS SLOS068P - JUNE 1976 - REVISED SEPTEMBER 2004

	DADAMETED	TEST CON	T. 1	L	M358A		UNIT		
	PARAMETER	TEST CON	יפאטוווטו	T <sub>A</sub> ‡	MIN	TYP§	MAX	UNII	
V <sub>1</sub> =	Input offset voltage	V <sub>CC</sub> = 5 V to 30 V	/,	25°C		2	3	mV	
V <sub>IO</sub>	input offset voltage	VIC = VICR(min)	V <sub>O</sub> = 1.4 V	Full range			5	mv	
$\alpha_{V_{IO}}$	Average temperature coefficient of input offset voltage			Full range		7	20	μV/°C	
1	locate offers at assument	V- 4.4V	25°C		2	30	A		
lio	Input offset current	V <sub>O</sub> = 1.4 V		Full range			75	nA	
$\alpha_{I}$ 10	Average temperature coefficient of input offset current			Full range		10	300	pA/°C	
	land bing some of	V 44V				-15	-100	A	
I <sub>IB</sub>	Input bias current	V <sub>O</sub> = 1.4 V		Full range			-200	nA	
Vion Common-mode input voltage range		V 00 V		25°C	0 to V <sub>CC</sub> – 1.	5		V	
VICR	Common-mode input voltage range	V <sub>CC</sub> = 30 V	Full range	0 to V <sub>CC</sub> -2			V		
		$R_L \ge 2 k\Omega$		25°C	V <sub>CC</sub> – 1	.5			
VOH	High-level output voltage	V <sub>CC</sub> = 30 V	$R_L = 2 k\Omega$	Full range	26			V	
		ACC = 30 A	$R_L \ge 10 \text{ k}\Omega$	Full range	27	28			
VOL	Low-level output voltage	R <sub>L</sub> ≤ 10 kΩ		Full range		5	20	mV	
AVD	Large-signal differential	V <sub>CC</sub> = 15 V, V <sub>O</sub> =	= 1 V to 11 V,	25°C	25	100		V/mV	
^VD	voltage amplification	$R_L \ge 2 k\Omega$		Full range	15			V/111V	
CMRR	Common-mode rejection ratio			25°C	65	80		dB	
ksvr	Supply-voltage rejection ratio $(\Delta V_{DD}/\Delta V_{IO})$			25°C	65	100		dB	
V <sub>O1</sub> /V <sub>O2</sub>	Crosstalk attenuation	f = 1 kHz to 20 kH	lz	25°C		120		dB	
		V <sub>CC</sub> = 15 V, V <sub>ID</sub> = 1 V,	Source	25°C	-20	-30	-60		
		$V_O = 0$	Source	Full range	-10			mA	
IO	Output current	$V_{CC} = 15 \text{ V},$ $V_{ID} = -1 \text{ V},$	Sink	25°C	10	20			
		V <sub>O</sub> = 15 V	SINK	Full range	5				
		$V_{ID} = -1 \text{ V}, V_{O} = 200 \text{ mV}$		25°C		30		μΑ	
los	Short-circuit output current	V <sub>CC</sub> at 5 V, GND	at $-5 \text{ V}, \text{ V}_0 = 0$	25°C		±40	±60	mA	
lcc	Supply current (two amplifiers)	V <sub>O</sub> = 2.5 V, No loa	Full range		0.7	1.2	mA		
100	Supply culteric (two amplifiers)	V <sub>CC</sub> = MAX, V <sub>O</sub> :	Full range		1	2	111/5		

<sup>†</sup> All characteristics are measured under open-loop conditions, with zero common-mode input voltage, unless otherwise specified. MAX V<sub>CC</sub> for testing purposes is 26 V for LM2904 and 30 V for others.



Full range is -55°C to 125°C for LM158A, -25°C to 85°C for LM258A, and 0°C to 70°C for LM358A.

<sup>§</sup> All typical values are at  $T_A = 25$ °C.

# operating conditions, $V_{CC}$ = $\pm 15$ V, $T_A$ = $25^{\circ}C$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
SR	Slew rate at unity gain	$R_L = 1 \text{ M}\Omega$ , $C_L = 30 \text{ pF}$ , $V_I = \pm 10 \text{ V}$ (see Figure 1)	0.3	V/μs
В1	Unity-gain bandwidth	$R_L = 1 M\Omega$ , $C_L = 20 pF$ (see Figure 1)	0.7	MHz
Vn	Equivalent input noise voltage	R <sub>S</sub> = 100 $\Omega$ , V <sub>I</sub> = 0 V, f = 1 kHz (see Figure 2)	40	nV/√ <del>Hz</del>

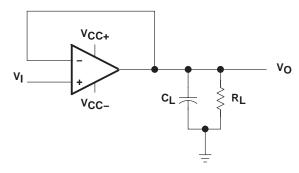


Figure 1. Unity-Gain Amplifier

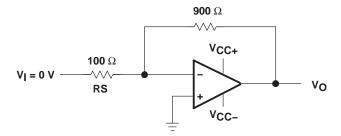


Figure 2. Noise-Test Circuit



### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
5962-87710012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
5962-8771001PA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
5962-87710022A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
5962-8771002PA	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
LM158AFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
LM158AJG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
LM158AJGB	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
LM158FKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	Level-NC-NC-NC
LM158JG	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
LM158JGB	ACTIVE	CDIP	JG	8	1	TBD	A42 SNPB	Level-NC-NC-NC
LM258AD	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM258ADGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM258ADR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM258AP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
LM258D	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM258DGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM258DR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM258P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
LM2904AVQDR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR/ Level-1-235C-UNLIM
LM2904AVQPWR	ACTIVE	TSSOP	PW	8	2000	TBD	Call TI	Level-1-250C-UNLIM
LM2904D	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
LM2904DGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM2904DR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR Level-1-235C-UNLIM
LM2904P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
LM2904PSR	ACTIVE	SO	PS	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR
LM2904PW	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM2904PWE4	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	Call TI	Level-1-250C-UNLIM
LM2904PWLE	OBSOLETE	TSSOP	PW	8		TBD	Call TI	Call TI
LM2904PWR	ACTIVE	TSSOP	PW	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM2904QD	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI





17-May-2005

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
LM2904QDR	OBSOLETE	SOIC	D	8		Pb-Free (RoHS)	Call TI	Level-2-250C-1 YEAR Level-1-235C-UNLIM
LM2904QP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
LM2904VQDR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-250C-1 YEAR Level-1-235C-UNLIM
LM2904VQPWR	ACTIVE	TSSOP	PW	8	2000	TBD	CU NIPDAU	Level-1-250C-UNLIM
LM358AD	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR Level-1-235C-UNLIM
LM358ADGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM358ADR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR Level-1-235C-UNLIM
LM358AP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
LM358APW	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	Call TI	Level-1-250C-UNLIM
LM358APWE4	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	Call TI	Level-1-250C-UNLIM
LM358APWR	ACTIVE	TSSOP	PW	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM358APWRE4	ACTIVE	TSSOP	PW	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM358D	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR Level-1-235C-UNLIM
LM358DGKR	ACTIVE	MSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
LM358DR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR Level-1-235C-UNLIM
LM358DRE4	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR Level-1-235C-UNLIM
LM358P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
LM358PSLE	OBSOLETE	SO	PS	8		TBD	Call TI	Call TI
LM358PSR	ACTIVE	SO	PS	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR Level-1-235C-UNLIM
LM358PW	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM358PWE4	ACTIVE	TSSOP	PW	8	150	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
LM358PWLE	OBSOLETE	TSSOP	PW	8		TBD	Call TI	Call TI
LM358PWR	ACTIVE	TSSOP	PW	8	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM

(1) The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check



#### PACKAGE OPTION ADDENDUM

17-May-2005

http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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### JG (R-GDIP-T8)

#### **CERAMIC DUAL-IN-LINE**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

#### FK (S-CQCC-N\*\*)

#### **28 TERMINAL SHOWN**

#### **LEADLESS CERAMIC CHIP CARRIER**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. The terminals are gold plated.
- E. Falls within JEDEC MS-004



#### P (R-PDIP-T8)

#### PLASTIC DUAL-IN-LINE



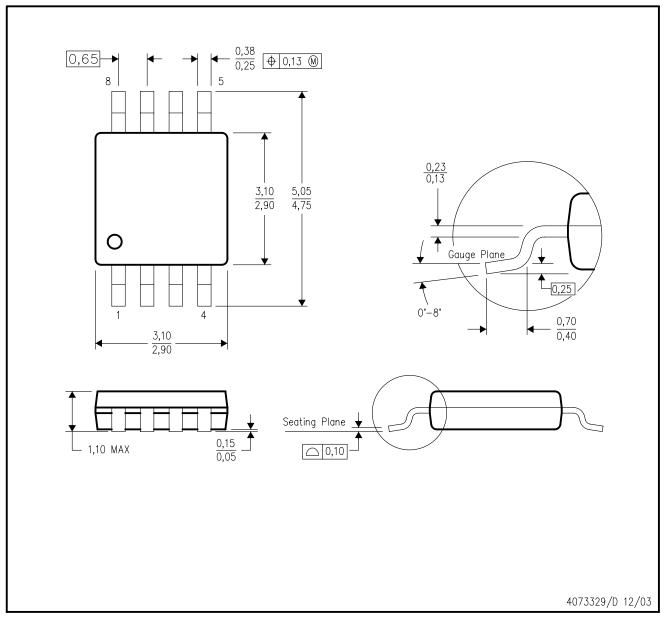
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001

For the latest package information, go to  $http://www.ti.com/sc/docs/package/pkg\_info.htm$ 

# DGK (S-PDSO-G8)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation AA.



# D (R-PDSO-G8)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



### PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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